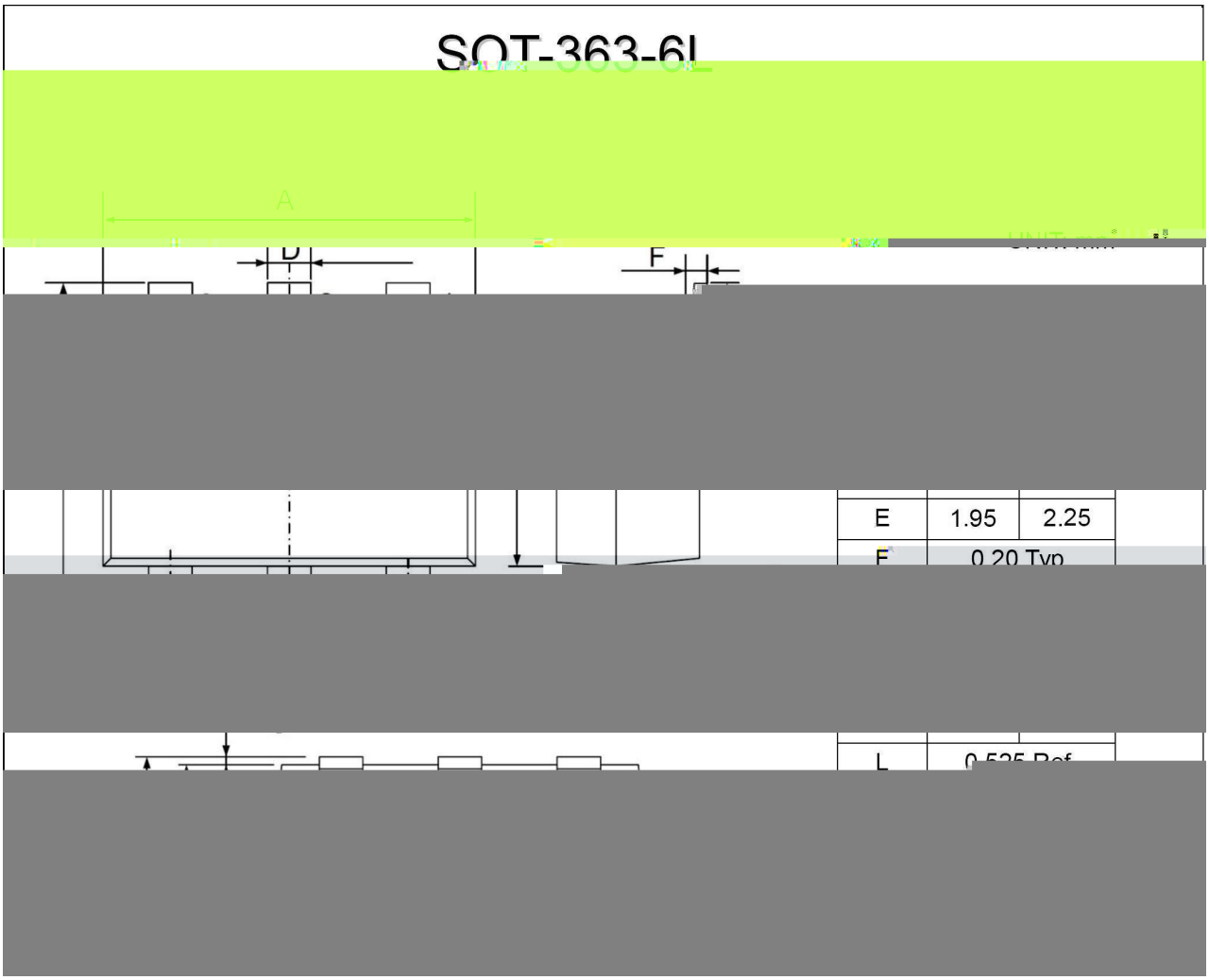
O P P 2 Q R S T U V W X
ilicon PNP transistor in a SOT-363 Plastic Package.

Y FE Z [CE(sat) X C D \ ] X
High DC Current Gain, Low Collector to Emitter Saturation Voltage. HF Product.

^ _ ` a b c) d e X
General purpose amplifier and switching.

g h Parameter	i j Symbol	h k Rating	l m Unit
Collector to Base Voltage	V_{CBO}	-40	V
Collector to Emitter Voltage	V_{CEO}	-40	V
Emitter to Base Voltage	V_{EBO}	-5.0	V
Collector Current	I_C	-200	mA

/ Package Dimensions



/ Marking Instructions

v w f

● f x y 1 z {

A2 f x u j | '

***: x } \ ~ j | ' Z } \ ~ j ¡ ¢

( ) / Temperature Profile for IR Reflow Soldering(Pb-Free)



		Note:
1	150 180 60 90sec;	1.Preheating:150~180 , Time:60~90sec.
2	245±5 5±0.5sec;	2.Peak Temp.:245±5 , Duration:5±0.5sec.
3	2 10 /sec.	3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

260±5	10±1 sec.	Temp.:260±5℃	Time:10±1 sec

/ Packaging SPEC.

/ REEL

Package Type 封装形式	Units 包装数量